

Supplemental Information for

V-VO₂ Core-shell Structure for Potential Thermal Switching

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This file includes:

Fig. S1, Fig. S2 and Fig. S3.

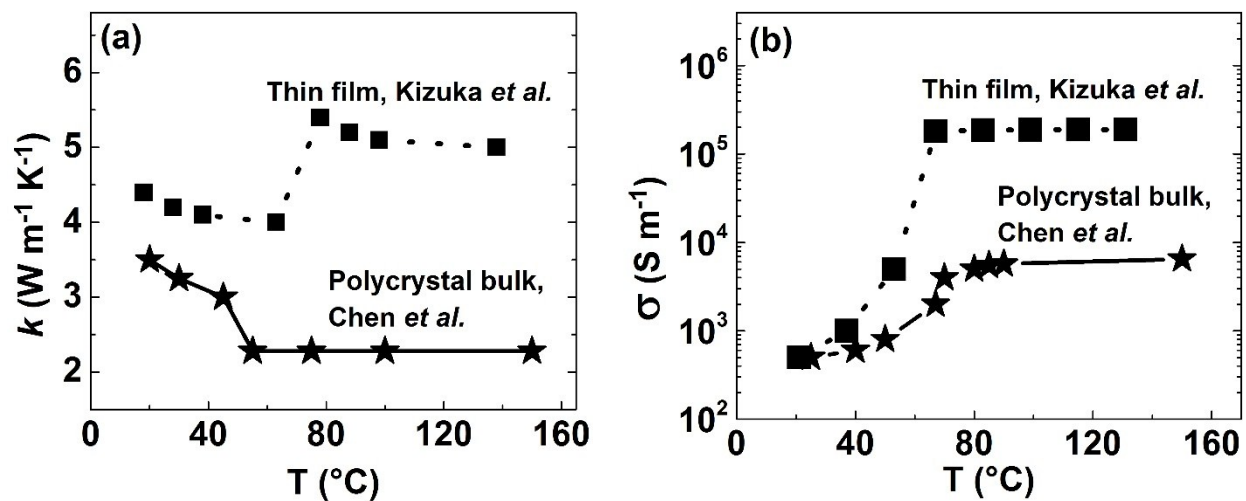


Fig. S1: Reported (a) thermal conductivity, and (b) electrical conductivity of different VO₂

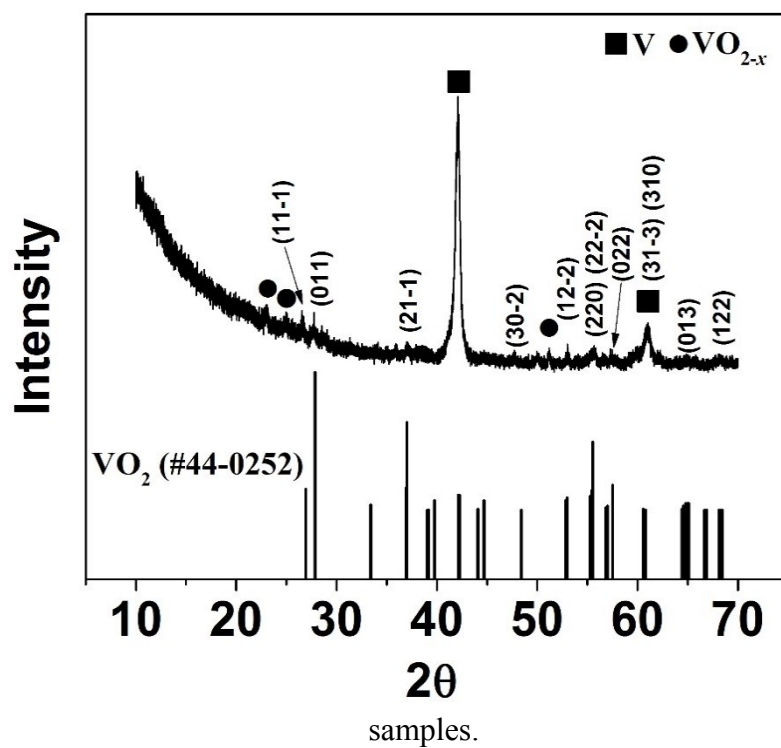


Fig. S2: XRD pattern of polished surface of V bar sample annealed at 350 °C + 380 °C + 425 °C for 7+7+7 hour.

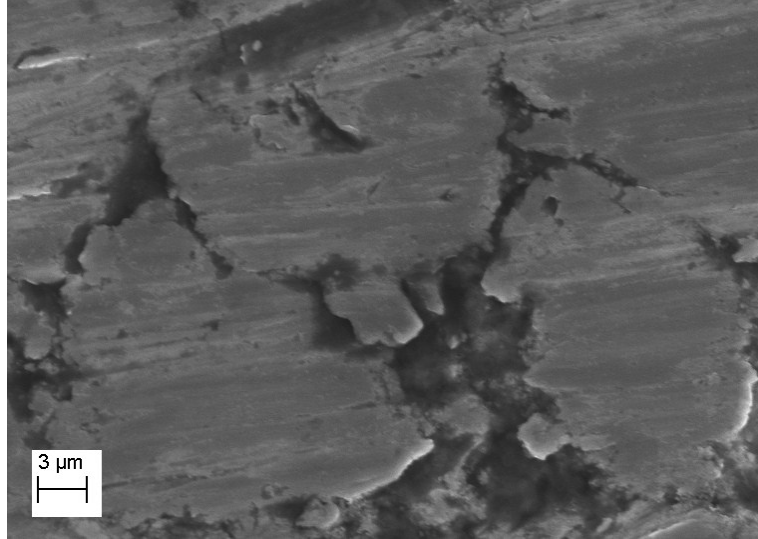


Fig. S3: SEM image of V-VO₂ sample annealed at 350 °C + 380 °C + 425 °C for 7+7+7 hour, showing the isolation of V particle separated by VO₂.